

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1-14. (Canceled).

15. (Currently Amended) An electroluminescent device, comprising:

a bank defining a plurality of pixels, each of the pixels having at least:

~~a TFT device, a substrate,~~

~~an at least one striped anode provided above the TFT device, substrate,~~

a light-emitting layer provided above the anode,

a thin-film layer provided above the light-emitting layer, and

~~a at least one striped cathode provided above the thin-film layer,~~

the bank defining the plurality of pixels by being provided above the substrate

so that the bank and the light-emitting layer are non-overlapping,

the thin-film layer being continuously formed so as to cover the plurality of

~~pixels and pixels,~~ being continuously formed so as to cover the light-emitting layer and the

bank, and

the cathode being continuously formed so as to cover the plurality of pixels,

the cathode disposed to orthogonally cross the anode.

16. (Canceled).

17. (Previously Presented) The electroluminescent device according to claim 15, the thin-film layer suppressing current flowing through the light-emitting layer and not contributing to light emission.

18. (Canceled).

19. (Previously Presented) The electroluminescent device according to claim 15, the bank overlapping edges of the anode.

20. (Original) The electroluminescent device according to claim 15, further comprising:

a hole injection layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

21. (Original) The electroluminescent device according to claim 15, further comprising:

a buffer layer having electrical conductivity, the thickness thereof being not less than 100 nm, disposed between the light-emitting layer and the anode.

22. (Currently Amended) The electroluminescent device according to claim 15, ~~further comprising wherein the light-emitting layer includes~~ an organic polymer including at least one of polyfluorene and a derivative of polyfluorene.

23. (Currently Amended) The electroluminescent device according to claim 15, ~~further comprising wherein the light-emitting layer includes~~ an organic polymer including at least one of poly(p-phenylenevinylene) and a derivative of poly(p-phenylenevinylene).

24. (Currently Amended) The electroluminescent device according to claim 15, ~~further comprising wherein the light-emitting layer includes an organic polymer with a degree of polymerization of an organic polymer~~ being at least two.

25. (Original) The electroluminescent device according to claim 15, the light-emitting layer being formed by depositing a plurality of light-emitting material layers.

26. (Previously Presented) An electronic device having the electroluminescent device according to claim 15.

27-42. (Canceled).